## NSN 5961-00-902-3444

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Inclosure Material:

Metal

**Overall Length:** 

1.803 inches

**Overall Diameter:** 

0.875 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

Thread Size:

0.312 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

55.0 base to emitter voltage, dc and 40.0 collector to emitter voltage, dc and 15.0 emitter to base voltage, static, collector open

**Current Rating Per Characteristic:** 

Between 7.50 amperes source cutoff current and 20.00 amperes source cutoff current

**Power Rating Per Characteristic:** 

200.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: npn

**Thread Series Designator:** 

Unf

**Terminal Type And Quantity:** 

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0